

Dual SCR Power Modules are designed for use in power electronic circuits and equipment under normal operating conditions.

**KEY PARAMETERS**

$U_{DRM}, U_{RRM}$	up to 1600 V
$I_{T(AV)}$	106 A
$I_{TSM}$	2500 A
$du/dt^*$	500 V/ $\mu$ s
$di/dt$	100 A/ $\mu$ s

\* maximum (non standard) value

**Outline**

See package details for further information

**APPLICATION**

- High Voltage Power Supplies
- Motor Control

**FEATURES**

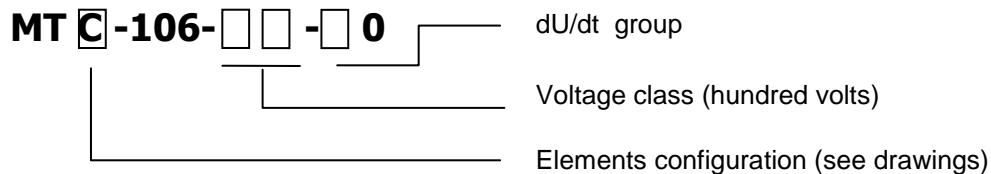
- electrically isolated base
- high current capabilities
- high surge current capabilities
- high rates voltages
- low thermal impedance (Aluminium Nitride Insulators)
- tested according to IEC standards
- compact size and small weight

Designed for use in high power industrial and commercial power electronic circuits and equipment where high currents are encountered and high reliability is essential.

**ORDERING INFORMATION**

When ordering please refer to device code builder presented below.

Please use the complete part number when ordering, quote or in any future correspondence relating to your order.



**ELECTRICAL PARAMETERS****Voltage ratings**

Voltage class	$U_{RRM}$	$U_{RSM}$	$I_{RRM}$
	V	V	mA
04	400	500	20
06	600	700	
08	800	900	
10	1000	1100	
12	1200	1300	
14	1400	1500	
16	1600	1700	

**dU/dt group codes**

Group code	du/dt
	V/ $\mu$ s
0	no specified value
5	320
6	500

### Electrical properties

Parameter		Unit	Test conditions	Value
Average on-state current	$I_{T(AV)}$	A		106
Case temperature	$T_C$	°C		85
RMS on-state current	$I_{T(RMS)}$	A		166
Surge current	$I_{TSM}$	A	$T_j=125^\circ\text{C}$ , $U_R=0,8U_{RRM}$ , $t_p=10\text{ms}$	2250
$I^2t$ – value	$I^2t$	$\text{kA}^2\text{s}$		25
On-state voltage max.	$U_{TM}$	V	$T_j=25^\circ\text{C}$ , $I_{TM}=300\text{A}$	1,65
Threshold voltage	$U_{T(TO)}$	V		0,9
Slope resistance	$r_T$	$\text{m}\Omega$		2,0
Latching current	$I_L$	mA	$T_j=25^\circ\text{C}$ , $U_D=12\text{V}$	600
Holding current	$I_H$	mA	$T_j=25^\circ\text{C}$ , $U_D=12\text{V}$	250
Circuit commutated turn-off time (typical)	$t_q$	$\mu\text{s}$	$T_j=125^\circ\text{C}$ , $I_{TM}=150\text{A}$ , $di_R/dt=12,5\text{A}/\mu\text{s}$ , $du/dt=20\text{V}/\mu\text{s}$ , $U_D=0,67U_{DRM}$ , $U_{RM}=100\text{V}$	100
Turn-On time (typical)	$t_{gt}$	$\mu\text{s}$	$I_{TM}=100\text{A}$ , $U_{DM}=100\text{V}$	10
Rate of rise of on-state current-repetitive	$di/dt$	$\text{A}/\mu\text{s}$	$T_j=125^\circ\text{C}$ , $I_{TM}=3I_{T(AV)}$ , $U_D=0,67U_{DRM}$ , $f=50\text{Hz}$ , $I_{GM}=1\text{A}$ , $di_G/dt=1\text{A}/\mu\text{s}$	100
Critical rate of raise of off-state voltage	$du/dt$	$\text{V}/\mu\text{s}$	$T_j=125^\circ\text{C}$ , $U_D=0,67U_{DRM}$ ,	320
Gate current to trigger	$I_{GT}$	mA	$T_j=25^\circ\text{C}$ , $U_D=12\text{V}$	100
Gate voltage to trigger	$U_{GT}$	V	$T_j=25^\circ\text{C}$ , $U_D=12\text{V}$	3
RMS isolation voltage	$U_{isol}$	V	1s, circuit to base, all terminals shorted	3000

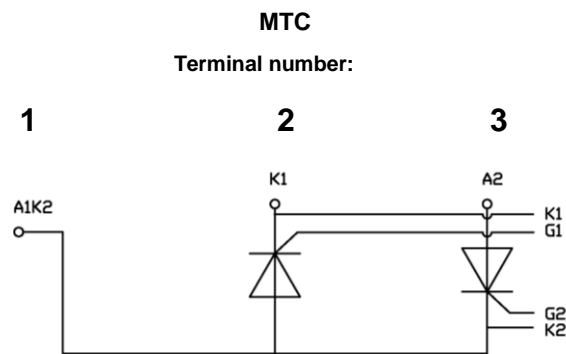
### Thermal properties

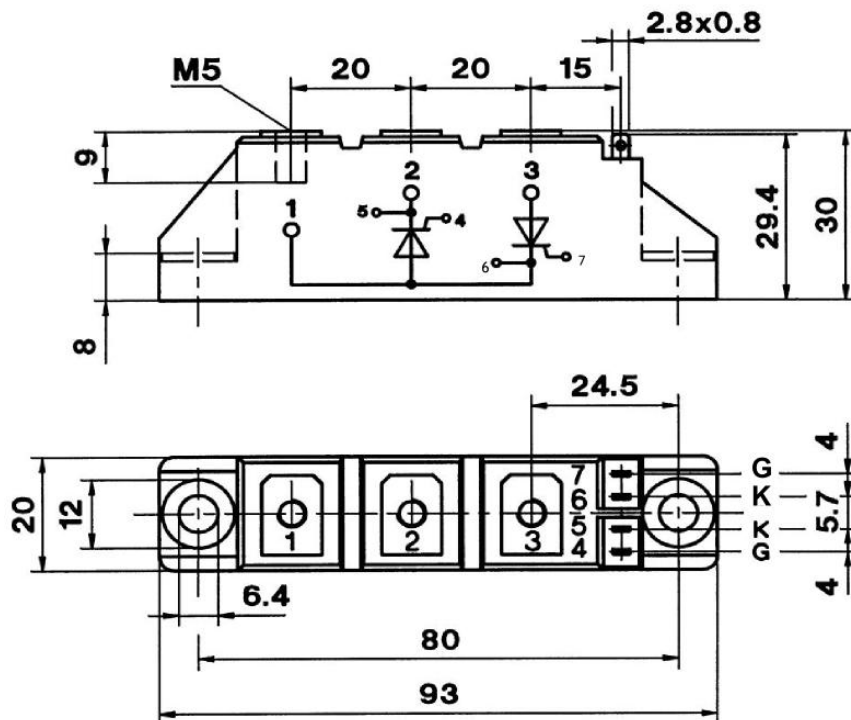
Parameter		Unit	Test conditions	Value
Thermal resistance, junction to case per thyristor/module	$R_{thJC}$	°C/W	DC	0,28/0,14
Thermal resistance, case to heatsink per thyristor/module	$R_{thCh}$	°C/W		0,20/0,10
Operating junction temperature	$T_{jmin} \dots T_{jmax}$	°C		-40...+125
Storage temperature	$T_{stg}$	°C		-40...+125

**Mechanical properties**

Parameter		Unit	Value
Mounting torque	M1	Nm	5,00 ±15%
Terminal connection torque (M5)	M2	Nm	3,00 ±15%
Weight	M	g	95

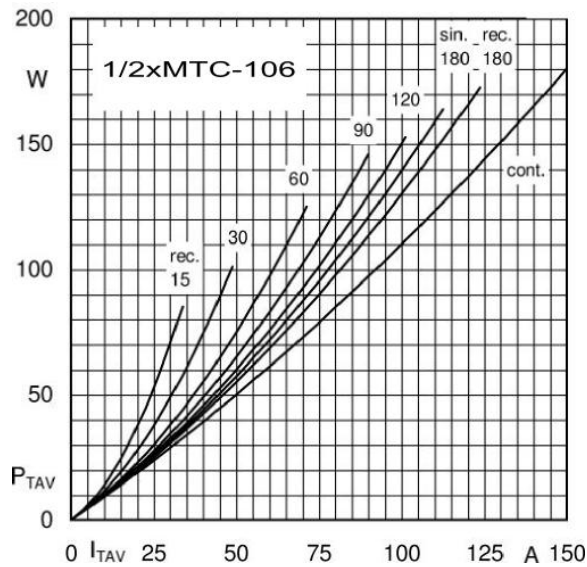
**Cofigurations**



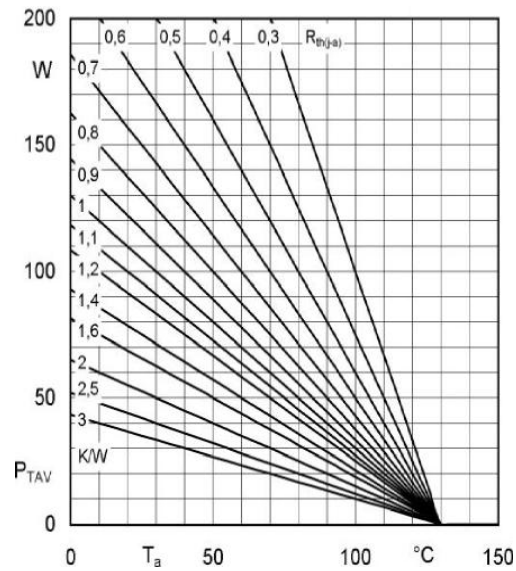
**Package details**

For further package information, please contact Sales & Marketing Department. All dimensions in mm, unless stated otherwise.  
Do not scale.

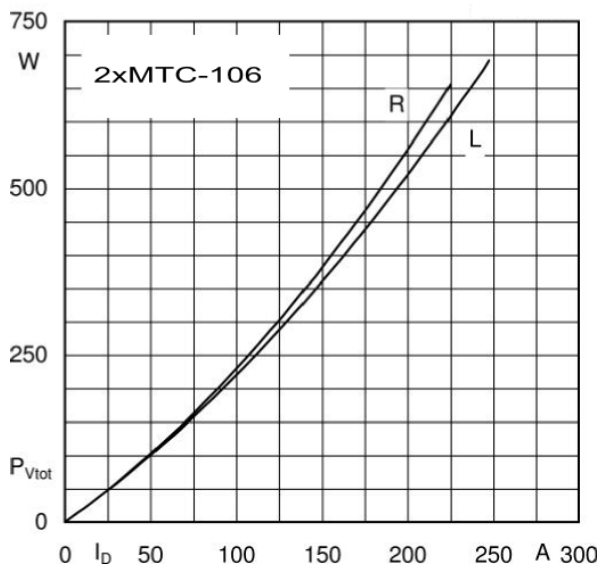
**CHARACTERISTICS**



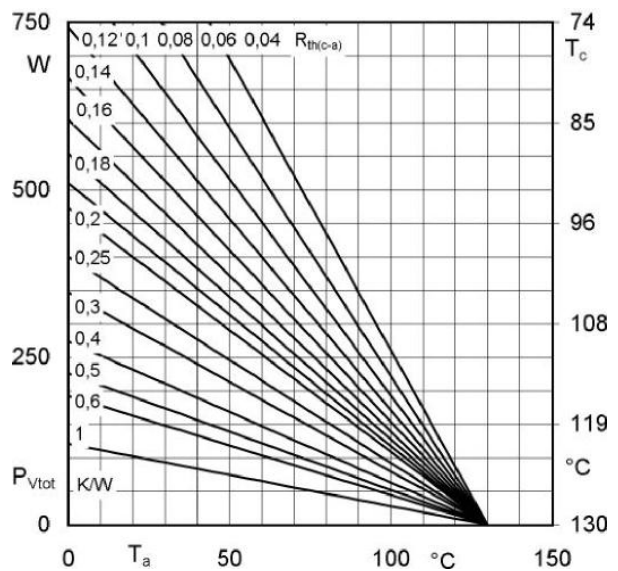
Power loss characteristics



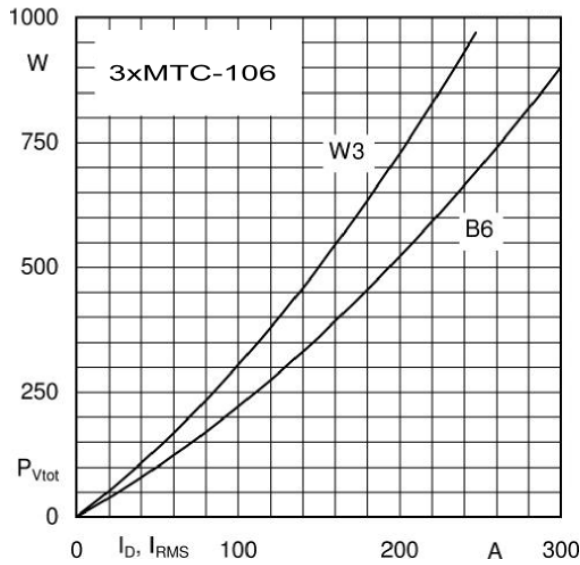
Power loss per diode vs ambient temperature



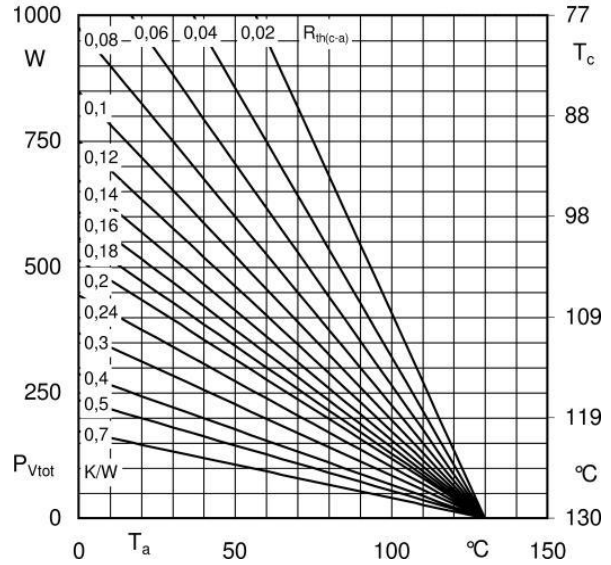
Power loss characteristics of two modules



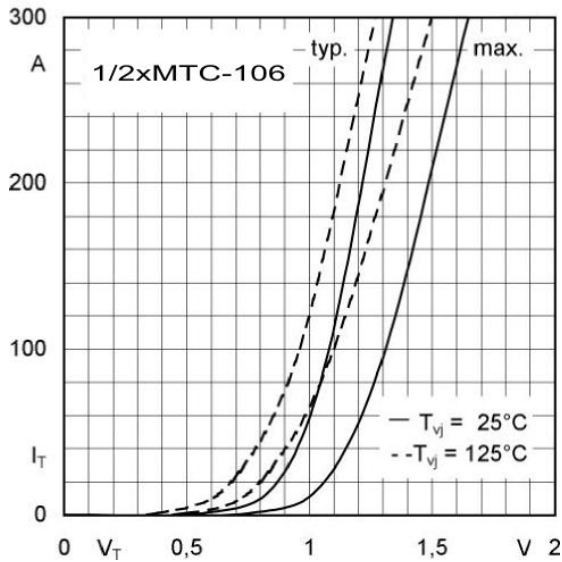
Power loss of two module vs case temperature



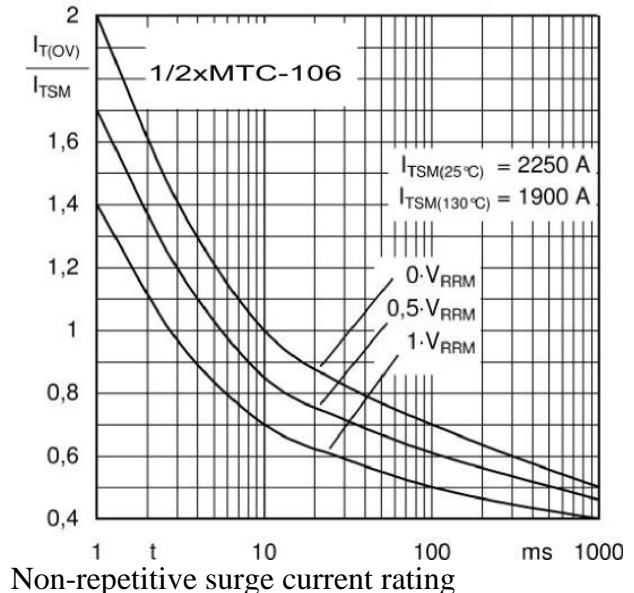
Power loss characteristics of three module



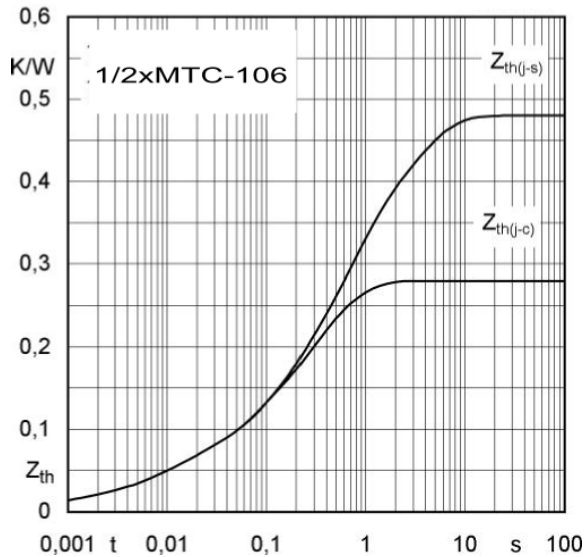
Power loss of three modules vs case temperature



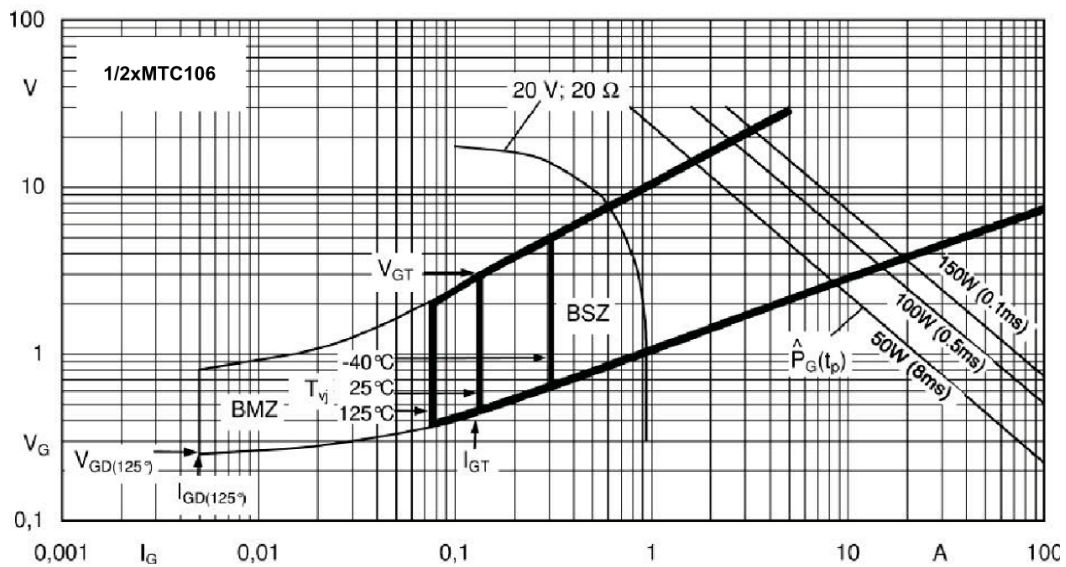
Forward characteristic



Non-repetitive surge current rating



Transient thermal impedance



Gate trigger characteristic